

FEATURES:

- Typical $t_{sk(o)}$ (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- $V_{CC} = 3.3V \pm 0.3V$, Normal Range
- $V_{CC} = 2.7V$ to $3.6V$, Extended Range
- CMOS power levels (0.4 μ W typ. static)
- All inputs, outputs, and I/O are 5V tolerant
- Available in TSSOP package

DRIVE FEATURES:

- Balanced Output Drivers: $\pm 12mA$
- Full internal series termination

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- Data communication and telecommunication systems

DESCRIPTION:

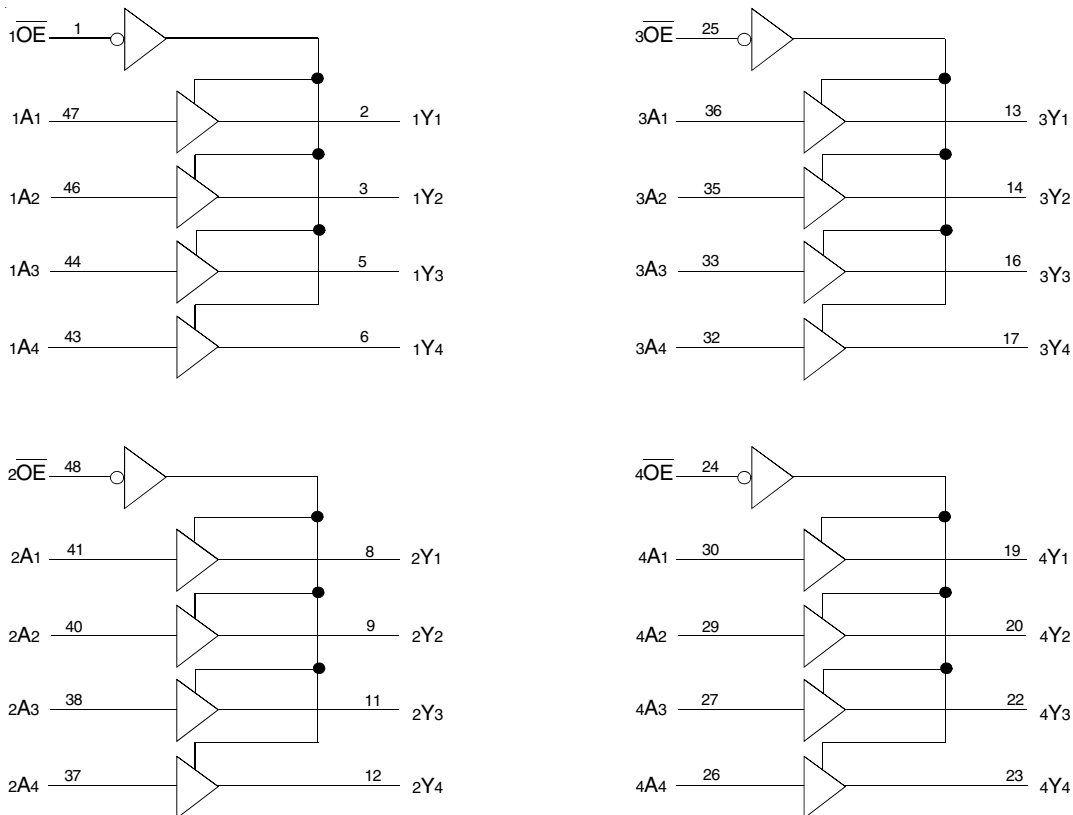
The LVCH162244A 16-bit buffer/driver is built using advanced dual metal CMOS technology. The LVCH162244A is designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. This device provides true outputs and symmetrical active-low output-enable (\overline{OE}) inputs.

All pins of this 16-bit buffer/driver can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V supply system.

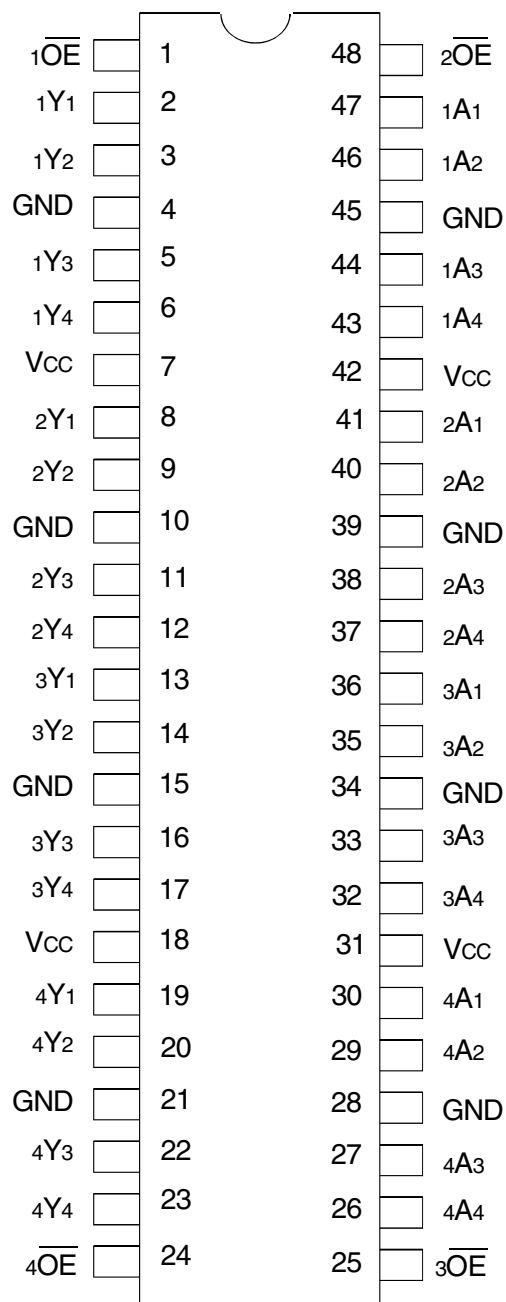
The LVCH162244A has series resistors in the device output structure which will significantly reduce line noise when used with light loads. This driver has been developed to drive $\pm 12mA$ at the designated threshold levels.

The LVCH162244A has "bus-hold" which retains the inputs' last state whenever the input goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



TSSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

| Symbol | Description | Max | Unit |
|------------------------------------|---|--------------|------|
| VTERM | Terminal Voltage with Respect to GND | -0.5 to +6.5 | V |
| TSTG | Storage Temperature | -65 to +150 | °C |
| IOUT | DC Output Current | -50 to +50 | mA |
| I _{IK} I _{OK} | Continuous Clamp Current, V _I < 0 or V _O < 0 | -50 | mA |
| I _{CC} I _{SS} | Continuous Current through each V _{CC} or GND | ±100 | mA |

NOTE:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (T_A = +25°C, F = 1.0MHz)

| Symbol | Parameter ⁽¹⁾ | Conditions | Typ. | Max. | Unit |
|------------------|--------------------------|-----------------------|------|------|------|
| C _{IN} | Input Capacitance | V _{IN} = 0V | 4.5 | 6 | pF |
| C _{OUT} | Output Capacitance | V _{OUT} = 0V | 6.5 | 8 | pF |
| C _{I/O} | I/O Port Capacitance | V _{IN} = 0V | 6.5 | 8 | pF |

NOTE:

- As applicable to the device type.

PIN DESCRIPTION

| Pin Names | Description |
|-------------------|---|
| x \overline{OE} | 3-State Output Enable Inputs (Active LOW) |
| xAx | Data Inputs ⁽¹⁾ |
| xYx | 3-State Outputs |

NOTE:

- These pins have "Bus-Hold". All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLE (EACH 4-BIT BUFFER)⁽¹⁾

| Inputs | | Outputs |
|-------------------|-----|---------|
| x \overline{OE} | xAx | xYx |
| L | L | L |
| L | H | H |
| H | X | Z |

NOTE:

- H = HIGH Voltage Level
X = Don't Care
L = LOW Voltage Level
Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$

| Symbol | Parameter | Test Conditions | | Min. | Typ. ⁽¹⁾ | Max. | Unit |
|--|--|---|---|------|---------------------|------|------|
| V _{IH} | Input HIGH Voltage Level | V _{CC} = 2.3V to 2.7V | | 1.7 | — | — | V |
| | | V _{CC} = 2.7V to 3.6V | | 2 | — | — | |
| V _{IL} | Input LOW Voltage Level | V _{CC} = 2.3V to 2.7V | | — | — | 0.7 | V |
| | | V _{CC} = 2.7V to 3.6V | | — | — | 0.8 | |
| I _{IH} I _{IL} | Input Leakage Current | V _{CC} = 3.6V | V _I = 0 to 5.5V | — | — | ±5 | μA |
| I _{OZH} I _{OZL} | High Impedance Output Current (3-State Output pins) | V _{CC} = 3.6V | V _O = 0 to 5.5V | — | — | ±10 | μA |
| I _{OFF} | Input/Output Power Off Leakage | V _{CC} = 0V, V _{IN} or V _O ≤ 5.5V | | — | — | ±50 | μA |
| V _{IK} | Clamp Diode Voltage | V _{CC} = 2.3V, I _{IN} = -18mA | | — | -0.7 | -1.2 | V |
| V _H | Input Hysteresis | V _{CC} = 3.3V | | — | 100 | — | mV |
| I _{CCL} I _{CCH} I _{CCZ} | Quiescent Power Supply Current | V _{CC} = 3.6V | V _{IN} = GND or V _{CC} | — | — | 10 | μA |
| | | | 3.6 ≤ V _{IN} ≤ 5.5V ⁽²⁾ | — | — | 10 | |
| ΔI _{CC} | Quiescent Power Supply Current Variation | One input at V _{CC} - 0.6V, other inputs at V _{CC} or GND | | — | — | 500 | μA |

NOTES:

1. Typical values are at V_{CC} = 3.3V, +25°C ambient.
2. This applies in the disabled state only.

BUS-HOLD CHARACTERISTICS

| Symbol | Parameter ⁽¹⁾ | Test Conditions | | Min. | Typ. ⁽²⁾ | Max. | Unit |
|--|----------------------------------|------------------------|----------------------------|------|---------------------|------|------|
| I _{BHH} I _{BHL} | Bus-Hold Input Sustain Current | V _{CC} = 3V | V _I = 2V | -75 | — | — | μA |
| | | | V _I = 0.8V | 75 | — | — | |
| I _{BHH} I _{BHL} | Bus-Hold Input Sustain Current | V _{CC} = 2.3V | V _I = 1.7V | — | — | — | μA |
| | | | V _I = 0.7V | — | — | — | |
| I _{BHHO} I _{BHLO} | Bus-Hold Input Overdrive Current | V _{CC} = 3.6V | V _I = 0 to 3.6V | — | — | ±500 | μA |

NOTES:

1. Pins with Bus-Hold are identified in the pin description.
2. Typical values are at V_{CC} = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

| Symbol | Parameter | Test Conditions ⁽¹⁾ | | Min. | Max. | Unit |
|-------------------------|---------------------|--------------------------------|--------------------------|-----------------------|------|------|
| VOH | Output HIGH Voltage | V _{CC} = 2.3V to 3.6V | I _{OH} = -0.1mA | V _{CC} - 0.2 | — | V |
| | | V _{CC} = 2.3V | I _{OH} = -4mA | 1.9 | — | |
| | | | I _{OH} = -6mA | 1.7 | — | |
| | | V _{CC} = 2.7V | I _{OH} = -4mA | 2.2 | — | |
| | | | I _{OH} = -8mA | 2 | — | |
| | | V _{CC} = 3V | I _{OH} = -6mA | 2.4 | — | |
| I _{OH} = -12mA | 2 | | — | | | |
| VOL | Output LOW Voltage | V _{CC} = 2.3V to 3.6V | I _{OL} = 0.1mA | — | 0.2 | V |
| | | V _{CC} = 2.3V | I _{OL} = 4mA | — | 0.4 | |
| | | | I _{OL} = 6mA | — | 0.55 | |
| | | V _{CC} = 2.7V | I _{OL} = 4mA | — | 0.4 | |
| | | | I _{OL} = 8mA | — | 0.6 | |
| | | V _{CC} = 3V | I _{OL} = 6mA | — | 0.55 | |
| I _{OL} = 12mA | — | | 0.8 | | | |

NOTE:
1. V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{CC} range. T_A = -40°C to +85°C.

OPERATING CHARACTERISTICS, T_A = 25°C

| Symbol | Parameter | Test Conditions | Typical | Unit |
|--------|--|---------------------------------|---------|------|
| CPD | Power Dissipation Capacitance per Buffer/Driver Outputs enabled | C _L = 0pF, f = 10Mhz | 35 | pF |
| CPD | Power Dissipation Capacitance per Buffer/Driver Outputs disabled | | 4 | |

SWITCHING CHARACTERISTICS⁽¹⁾

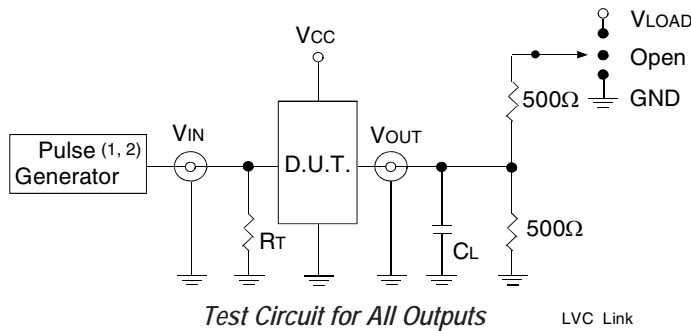
| Symbol | Parameter | V _{CC} = 2.7V | | V _{CC} = 3.3V ± 0.3V | | Unit |
|--------------------|----------------------------|------------------------|------|-------------------------------|------|------|
| | | Min. | Max. | Min. | Max. | |
| t _{PLH} | Propagation Delay | — | 5.6 | 1.1 | 4.4 | ns |
| t _{PHL} | xAx to xYx | | | | | |
| t _{PZH} | Output Enable Time | — | 6.9 | 1 | 5.5 | ns |
| t _{PZL} | x \overline{OE} to xYx | | | | | |
| t _{PHZ} | Output Disable Time | — | 6.8 | 1.8 | 6.3 | ns |
| t _{PLZ} | x \overline{OE} to xYx | | | | | |
| t _{SK(0)} | Output Skew ⁽²⁾ | — | — | — | 500 | ps |

NOTES:
1. See TEST CIRCUITS AND WAVEFORMS. T_A = -40°C to +85°C.
2. Skew between any two outputs of the same package and switching in the same direction.

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

| Symbol | V _{CC} ⁽¹⁾ =3.3V±0.3V | V _{CC} ⁽¹⁾ =2.7V | V _{CC} ⁽²⁾ =2.5V±0.2V | Unit |
|-------------------|---|--------------------------------------|---|------|
| V _{LOAD} | 6 | 6 | 2 x V _{CC} | V |
| V _{IH} | 2.7 | 2.7 | V _{CC} | V |
| V _T | 1.5 | 1.5 | V _{CC} / 2 | V |
| V _{LZ} | 300 | 300 | 150 | mV |
| V _{HZ} | 300 | 300 | 150 | mV |
| C _L | 50 | 50 | 30 | pF |



DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_r ≤ 2.5ns; t_r ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_r ≤ 2ns; t_r ≤ 2ns.

SWITCH POSITION

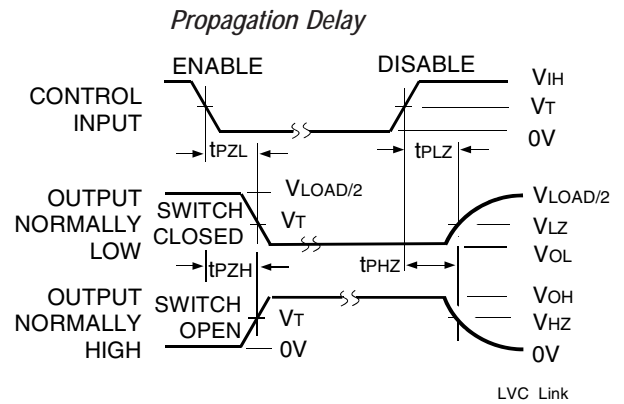
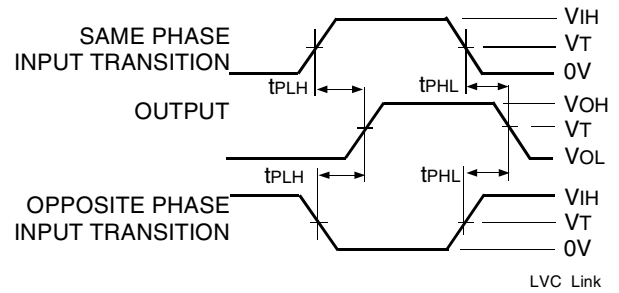
| Test | Switch |
|---|-------------------|
| Open Drain Disable Low Enable Low | V _{LOAD} |
| Disable High Enable High | GND |
| All Other Tests | Open |



$$t_{SK}(x) = |t_{PLH2} - t_{PLH1}| \text{ or } |t_{PHL2} - t_{PHL1}|$$

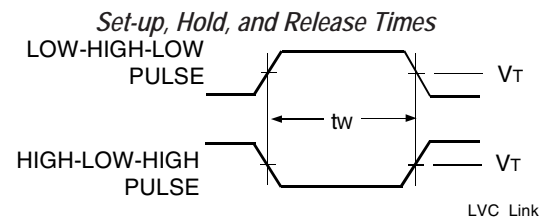
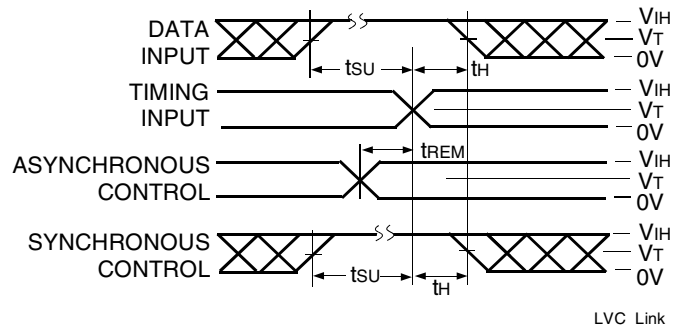
NOTES:

1. For t_{SK}(o) OUTPUT1 and OUTPUT2 are any two outputs.
2. For t_{SK}(b) OUTPUT1 and OUTPUT2 are in the same bank.



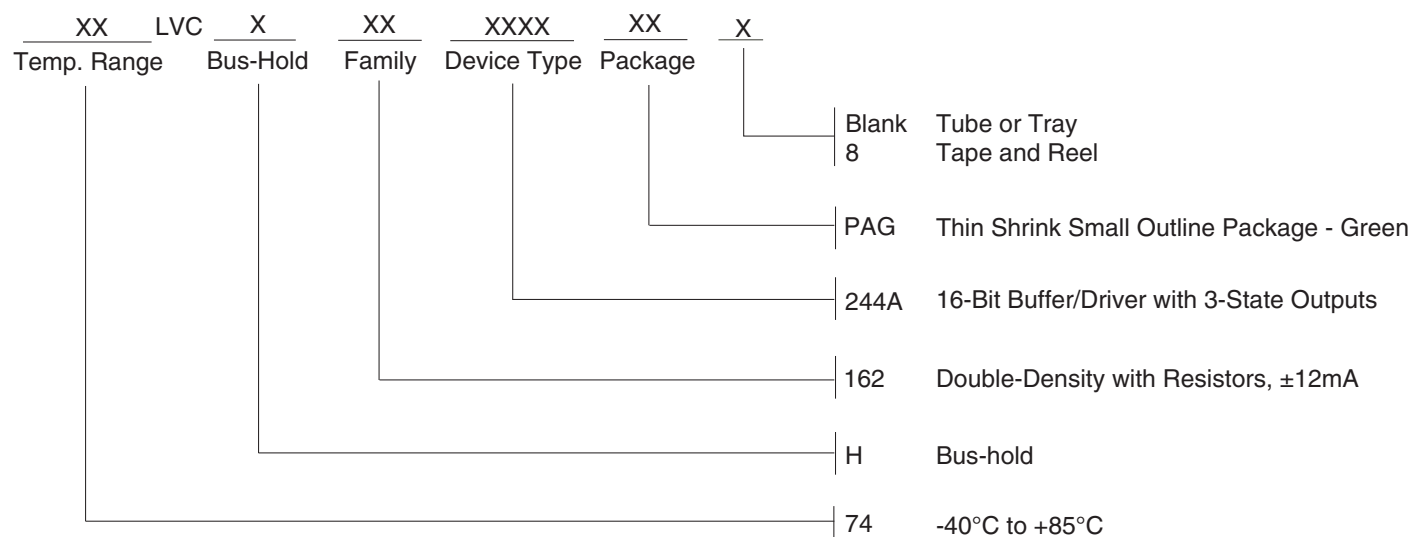
NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.



Pulse Width

ORDERING INFORMATION



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Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu,
Koto-ku, Tokyo 135-0061, Japan
www.renesas.com

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